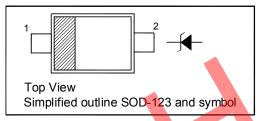
Silicon Planar Zener Diodes

Features

- Total power dissipation: max. 500 mW
- Small plastic package suitable for surface mounted design
- Tolerance approximately ± 5%

PINNING

PIN	DESCRIPTION
1	Cathode
2	Anode



Absolute Maximum Ratings ($T_a = 25$ °C)

Parameter		Symbol	Value	Unit
Power Dissipation		P _{tot}	500	mW
Junction Temperature		T _i	150	°C
Storage Temperature Range		T _{stg}	- 55 to + 150	°C

Characteristics at T_a = 25 °C

Parameter	Symbol	Max.	Unit
Thermal Resistance Junction to Ambient Air	R _{thA}	340	°C/W
Forward Voltage at I _E = 10 mA	V _F	0.9	V



MM1Z2V0~MM1Z75

Characteristics at $T_a = 25$ °C

	Marking	Zener Voltage Range 1)			Dynamic Im	pedance 2)	Reverse Leak	Reverse Leakage Current	
Type	Marking Code	V_{znom}	V_{ZT}	at I _{ZT}	Z_{ZT}	at I _{ZT}	I _R	at V _R	
	0000	V	V	mA	Max. (Ω)	mA	Max. (µA)	V	
MM1Z2V0	4A	2	1.82.15	5	100	5	120	0.5	
MM1Z2V2	4B	2.2	2.082.33	5	100	5	120	0.7	
MM1Z2V4	4C	2.4	2.282.56	5	100	5	120	1	
MM1Z2V7	4D	2.7	2.52.9	5	110	5	120	1	
MM1Z3V0	4E	3	2.83.2	5	120	5	50	1	
MM1Z3V3	4F	3.3	3.13.5	5	130	5	20	1	
MM1Z3V6	4H	3.6	3.43.8	5	130	5	10	1	
MM1Z3V9	4J	3.9	3.74.1	5	130	5	5	1	
MM1Z4V3	4K	4.3	44.6	5	130	5	5	1	
MM1Z4V7	4M	4.7	4.45	5	130	5	2	1	
MM1Z5V1	4N	5.1	4.85.4	5	130	5	2	1.5	
MM1Z5V6	4P	5.6	5.26	5	80	5	1	2.5	
MM1Z6V2	4R	6.2	5.86.6	5	50	5	1	3	
MM1Z6V8	4X	6.8	6.47.2	5	30	5	0.5	3.5	
MM1Z7V5	4Y	7.5	77.9	5	30	5	0.5	4	
MM1Z8V2	4Z	8.2	7.78.7	5	30	5	0.5	5	
MM1Z9V1	5A	9.1	8.59.6	5	30	5	0.5	6	
MM1Z10	5B	10	9.410.6	5	30	5	0.1	7	
MM1Z11	5C	11	10.411.6	5	30	5	0.1	8	
MM1Z12	5D	12	11.412.7	5	35	5	0.1	9	
MM1Z13	5E	13	12.414.1	5	35	5	0.1	10	
MM1Z15	5F	15	13.815.6	5	40	5	0.1	11	
MM1Z16	5H	16	15.3 <mark>.1</mark> 7.1	5	40	5	0.1	12	
MM1Z18	5J	18	16.819.1	5	45	5	0.1	13	
MM1Z20	5K	20	18.821.2	5	50	5	0.1	15	
MM1Z22	5M	22	20.823.3	5	55	5	0.1	17	
MM1Z24	5N	24	22.825.6	5	60	5	0.1	19	
MM1Z27	5P	27	25.128.9	5	70	2	0.1	21	
MM1Z30	5R	30	2832	5	80	2	0.1	23	
MM1Z33	5X	33	3135	5	80	2	0.1	25	
MM1Z36	5Y	36	3438	5	90	2	0.1	27	
MM1Z39	5Z	39	3741	2.5	100	2	2	30	
MM1Z43	6A	43	4046	2.5	130	2	2	33	
MM1Z47	6B	47	4450	2.5	150	2	2	36	
MM1Z51	6C	51	4854	2.5	180	2	1	39	
MM1Z56	6D	56	5260	2.5	180	2	1	43	
MM1Z62	6E	62	5866	2.5	200	2	0.2	47	
MM1Z68	6F	68	6472	2.5	250	2	0.2	52	
MM1Z75	6H	75	7079	2.5	300	2	0.2	57	

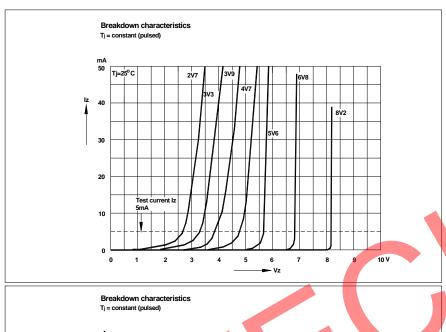


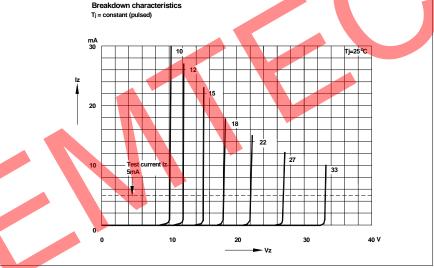


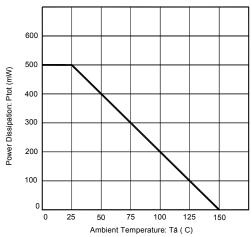




 $^{^{1)}}$ V_Z is tested with pulses (20 ms). $^{2)}$ Z_{ZT} is measured at I_Z by given a very small A.C. current signal.







Power Dissipation vs Ambient Temperature













PACKAGE OUTLINE

Plastic surface mounted package; 2 leads

SOD-123

